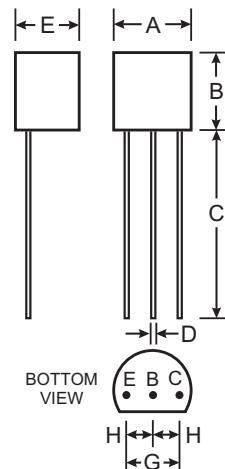


Features

- Ideal for Switching and AF Amplifier Applications
- Divided into Current Gain Subgroups
- Complementary PNP Types Available (BC556 - BC558)

Mechanical Data

- Case: TO-92, Plastic
- Leads: Solderable per MIL-STD-202, Method 208
- Pin Connections: See Diagram
- Weight: 0.18 grams (approx.)



TO-92		
Dim	Min	Max
A	4.45	4.70
B	4.46	4.70
C	12.7	—
D	0.41	0.63
E	3.43	3.68
G	2.42	2.67
H	1.14	1.40
All Dimensions in mm		

Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage BC546 BC547 BC548	V_{CBO}	80 50 30	V
Collector-Emitter Voltage BC546 BC547 BC548	V_{CEO}	65 45 30	V
Emitter-Base Voltage BC546, BC547 BC548	V_{EBO}	6.0 5.0	V
Collector Current	I_C	100	mA
Peak Collector Current	I_{CM}	200	mA
Peak Emitter Current	I_{EM}	200	mA
Power Dissipation (Note 1)	P_d	500	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	250	K/W
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150	°C

Notes:

1. Leads maintained at ambient temperature at a distance of 2mm from case.
2. Current gain subgroup "C" is not available for BC546.

Electrical Characteristics 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
h-Parameters Small Signal Current Gain	h_{fe}	—	220	—	—	
	h_{fe}	—	330	—	—	
	h_{fe}	—	600	—	—	
Input Impedance	h_{je}	1.6	2.7	4.5	kΩ	$V_{CE} = 5.0V, I_C = 2.0mA, f = 1.0kHz$, Note 2
	h_{je}	3.2	4.5	8.5	kΩ	
	h_{je}	6.0	8.7	15	kΩ	
Output Admittance	h_{oe}	—	18	30	μS	
	h_{oe}	—	30	60	μS	
	h_{oe}	—	60	110	μS	
Reverse Voltage Transfer Ratio	h_{re}	—	1.5×10^{-4}	—	—	
	h_{re}	—	4.2×10^{-4}	—	—	
	h_{re}	—	3×10^{-4}	—	—	
DC Current Gain	h_{fe}	—	90	—	—	Note 2 $V_{CE} = 5.0V, I_C = 10\mu A$
		—	150	—	—	
		—	270	—	—	
	Group A	110	180	220	—	$V_{CE} = 5.0V, I_C = 2.0mA$
	B	200	290	450	—	
	C	420	500	800	—	
	Group A	—	120	—	—	$V_{CE} = 5.0V, I_C = 100mA$
	B	—	200	—	—	
	C	—	400	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	80 200	200 600	mV	$I_C = 10mA, I_B = 0.5mA$ $I_C = 100mA, I_B = 5.0mA$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	700 900	—	mV	$I_C = 10mA, I_B = 0.5mA$ $I_C = 100mA, I_B = 5.0mA$
Base-Emitter Voltage	V_{BE}	580 —	660 —	700 720	mV	$V_{CE} = 5.0V, I_C = 2.0mA$ $V_{CE} = 5.0V, I_C = 10mA$
Collector Cutoff Current	I_{CES}	0.2	15	nA	V _{CE} = 80V	
BC556	I_{CES}	0.2	15	nA	V _{CE} = 50V	
BC557	I_{CES}	0.2	15	nA	V _{CE} = 30V	
BC558	I_{CES}	—	4.0	μA	$V_{CE} = 80V, T_j = 125^\circ C$	
BC556	I_{CES}	—	4.0	μA	$V_{CE} = 50V, T_j = 125^\circ C$	
BC557	I_{CES}	—	4.0	μA	$V_{CE} = 30V, T_j = 125^\circ C$	
BC558	I_{CES}	—	15	nA	$V_{CB} = 30V$	
	I_{CBO}	—	5.0	μA	$V_{CB} = 30V, T_j = 150^\circ C$	
Gain Bandwidth Product	f_T	—	300	—	MHz	$V_{CE} = 5.0V, I_C = 10mA, f = 100MHz$
Collector-Base Capacitance	C_{CBO}	—	3.5	6.0	pF	$V_{CB} = 10V, f = 1.0MHz$
Emitter-Base Capacitance	C_{EBO}	—	9	—	pF	$V_{EB} = 0.5V, f = 1MHz$
Noise Figure	NF	—	2.0	10	dB	$V_{CE} = 5.0V, I_C = 200\mu A, R_G = 2.0k\Omega, f = 1.0kHz, \Delta f = 200Hz$

Notes: 1. Leads maintained at ambient temperature at a distance of 2mm from case.
 2. Current gain subgroup "C" is not available for BC546.

